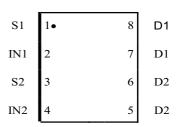


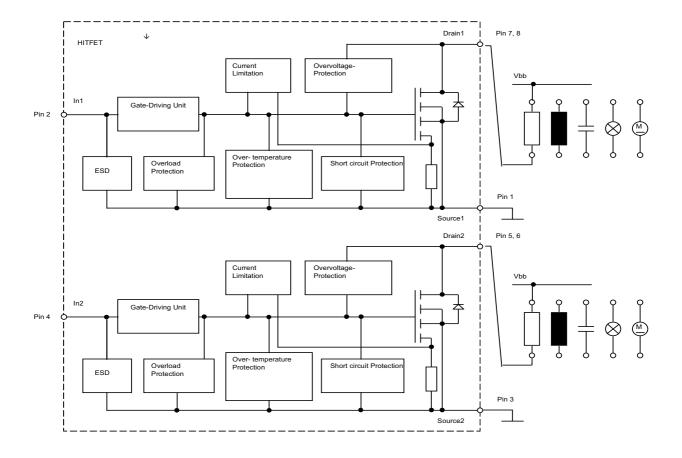
Pin Description

| Pin | Symbol | Function | |
|-----------------------|--------|--------------------|--|
| 1 | S1 | Source Channel 1 | |
| 2 IN1 Input Channel 1 | | Input Channel 1 | |
| 3 S2 Source Channel 2 | | Source Channel 2 | |
| 4 IN2 Input Channel 2 | | Input Channel 2 | |
| 5 | D2 | Drain Channel 2 | |
| 6 D2 Drain Channel | | Drain Channel 2 | |
| 7 D1 Drain Channel 1 | | Drain Channel 1 | |
| 8 | D1 | D1 Drain Channel 1 | |

Pin Configuration (Top view)



PG-DSO-8-25



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Maximum Ratings at T_i = 25°C, unless otherwise specified

| Parameter | Symbol | Value | Unit | |
|--|---------------------|------------------|------|--|
| Drain source voltage | $V_{\rm DS}$ | 42 | V | |
| Drain source voltage for short circuit protection 1) | V _{DS(SC)} | 18 | | |
| <i>T</i> _j = -40150 °C | , , | | | |
| Continuous input current ¹⁾ | / _{IN} | | mA | |
| $-0.2V \le V_{IN} \le 10V$ | | no limit | | |
| V_{IN} < -0.2V or V_{IN} > 10V | | $ I_{1N} \le 2$ | | |
| Operating temperature | T_{i} | -40+150 | °C | |
| Storage temperature | $T_{\rm stg}$ | -55 + 150 | | |
| Power dissipation ²⁾⁵⁾ | P _{tot} | 0.8 | W | |
| <i>T</i> _A = 85 °C | | | | |
| Unclamped single pulse inductive energy ¹⁾ | E _{AS} | 150 | mJ | |
| each channel | | | | |
| Load dump protection $V_{\text{LoadDump}}^{(1)3)} = V_{\text{A}} + V_{\text{S}}$ | V_{LD} | 50 | V | |
| $V_{\rm IN}$ = 0 and 10 V, $t_{\rm d}$ = 400 ms, $R_{\rm I}$ = 2 Ω , | | | | |
| $R_{L} = 9 \Omega, V_{A} = 13.5 V$ | | | | |
| Electrostatic discharge voltage1) (Human Body Model) | V _{ESD} | 2 | kV | |
| according to Jedec norm | | | | |
| EIA/JESD22-A114-B, Section 4 | | | | |
| | | | | |
| | | | | |

Thermal resistance

| junction - ambient: per channel | | R _{thJA} | | K/W |
|--|------------------|-------------------|-----|-----|
| @ 6 cm ² cooling area ²⁾ | one channel on | | 100 | |
| | both channels on | | 160 | |

¹not subject to production test, specified by design

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² Device on 50mm*50mm*1.5mm epoxy PCB FR4 with 6cm² (one layer, 70μm thick) copper area for drain connection. PCB mounted vertical without blown air.

 $^{^3}V_{
m Loaddump}$ is setup without the DUT connected to the generator per ISO 7637-1 and DIN 40839

 $^{^{5}}$ not subject to production test, calculated by $\rm R_{THJA}$ and $\rm R_{ds(on)}$



Electrical Characteristics

| Parameter | Symbol | Values | | | Unit |
|--|---------------------|--------|------|------|------|
| at T_j = 25°C, unless otherwise specified | | min. | typ. | max. | |
| Characteristics | | | | | |
| Drain source clamp voltage | $V_{\rm DS(AZ)}$ | 42 | - | 55 | V |
| $T_{\rm j}$ = -40+ 150, $I_{\rm D}$ = 10 mA | | | | | |
| Off-state drain current T _j = -40 +150°C | I _{DSS} | - | 1.5 | 10 | μA |
| $V_{\rm DS} = 32 \text{ V}, \ V_{\rm IN} = 0 \text{ V}$ | | | | | |
| Input threshold voltage | $V_{\rm IN(th)}$ | | | | V |
| $I_{\rm D}$ = 0.3 mA, $T_{\rm j}$ = 25 °C | | 1.3 | 1.7 | 2.2 | |
| $I_{\rm D}$ = 0.3 mA, $T_{\rm j}$ = 150 °C | | 0.8 | - | - | |
| On state input current | I _{IN(on)} | - | 10 | 30 | μΑ |
| On-state resistance | R _{DS(on)} | | | | mΩ |
| $V_{\rm IN}$ = 5 V, $I_{\rm D}$ = 1.4 A, $T_{\rm j}$ = 25 °C | | - | 190 | 240 | |
| $V_{\rm IN}$ = 5 V, $I_{\rm D}$ = 1.4 A, $T_{\rm j}$ = 150 °C | | - | 350 | 480 | |
| On-state resistance | R _{DS(on)} | | | | |
| $V_{\rm IN}$ = 10 V, $I_{\rm D}$ = 1.4 A, $T_{\rm j}$ = 25 °C | | - | 150 | 200 | |
| $V_{\rm IN}$ = 10 V, $I_{\rm D}$ = 1.4 A, $T_{\rm j}$ = 150 °C | | - | 280 | 400 | |
| Nominal load current per channel ⁵⁾ | I _{D(Nom)} | | | | Α |
| $V_{\rm DS}$ = 0.5 V, $T_{\rm j}$ < 150°C, $V_{\rm IN}$ = 10 V, $T_{\rm A}$ = 85 °C, | | | | | |
| one channel on | | 1.3 | 1.65 | _ | |
| both channels on | | 1 | 1.3 | _ | |
| Current limit (active if V _{DS} >2.5 V) ²⁾ | I _{D(lim)} | 5 | 7.5 | 10 | 1 |
| $V_{\rm IN}$ = 10 V, $V_{\rm DS}$ = 12 V, $t_{\rm m}$ = 200 $\mu {\rm s}$ | | | | | |

¹not subject to production test, specified by design

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²Device switched on into existing short circuit (see diagram Determination of $b_{(lim)}$). If the device is in on conc and a short circuit occurs, these values might be exceeded for max. 50 μ s.

 $^{^{5}}$ not subject to production test, calculated by $R_{\mbox{\scriptsize THJA}}$ and $R_{\mbox{\scriptsize ds(on)}}$



Electrical Characteristics

| Parameter | Symbol | Values | | | Unit | |
|--|-------------------------------------|--------|------|------|------|--|
| at T_j = 25°C, unless otherwise specified | | min. | typ. | max. | | |
| Dynamic Characteristics | | | | | | |
| Turn-on time V_{IN} to 90% I_{D} : | <i>t</i> on | ı | 45 | 100 | μs | |
| $R_{\rm L}$ = 4.7 Ω , $V_{\rm IN}$ = 0 to 10 V, $V_{\rm bb}$ = 12 V | | | | | | |
| Turn-off time V_{IN} to 10% I_{D} : | $t_{ m off}$ | - | 60 | 100 | | |
| $R_{\rm L}$ = 4.7 Ω , $V_{\rm IN}$ = 10 to 0 V, $V_{\rm bb}$ = 12 V | | | | | | |
| Slew rate on 70 to 50% $V_{\rm bb}$: | -dV _{DS} /dt _{on} | - | 0.4 | 1.5 | V/µs | |
| $R_{\rm L}$ = 4.7 Ω , $V_{\rm IN}$ = 0 to 10 V, $V_{\rm bb}$ = 12 V | | | | | | |
| Slew rate off 50 to 70% $V_{\rm bb}$: | dV _{DS} /dt _{off} | - | 0.6 | 1.5 | | |
| $R_{\rm L}$ = 4.7 Ω , $V_{\rm IN}$ = 10 to 0 V, $V_{\rm bb}$ = 12 V | | | | | | |
| Protection Functions ¹⁾ | | | | | | |
| Thermal overload trip temperature | $T_{\rm jt}$ | 150 | 175 | - | °C | |
| Thermal hysteresis ²⁾ | $\Delta T_{ m jt}$ | - | 10 | - | K | |
| Input current protection mode | I _{IN(Prot)} | 25 | 50 | 300 | μΑ | |
| Input current protection mode | I _{IN(Prot)} | - | 40 | 300 | | |
| <i>T</i> _j = 150 °C | | | | | | |
| Unclamped single pulse inductive energy ²⁾ | E _{AS} | 150 | - | - | mJ | |
| each channel | | | | | | |
| $I_D = 0.9 \text{ A}, T_j = 25 \text{ °C}, V_{bb} = 12 \text{ V}$ | | | | | | |
| Inverse Diode | | | | | | |
| Inverse diode forward voltage | V_{SD} | - | 1 | - | V | |
| I_{F} = 7 A, t_{m} = 250 µs, V_{IN} = 0 V, | | | | | | |
| $t_{\rm P}$ = 300 µs | | | | | | |

¹Integrated protection functions are designed to prevent IC destruction under fault conditions described in the data sheet. Fault conditions are considered as "outside" normal operating range. Protection functions are not designed for continuous repetitive operation

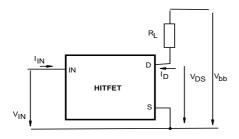
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²not subject to production test, specified by design

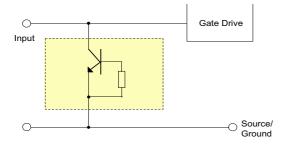


Block diagram

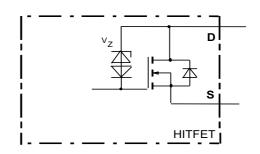
Terms



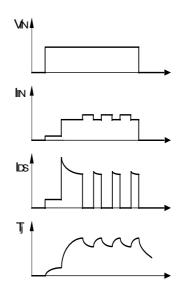
Input circuit (ESD protection)



Inductive and overvoltage output clamp



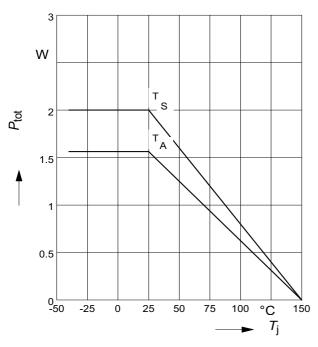
Short circuit behaviour





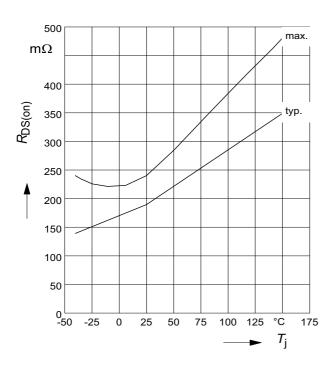
1 Overall maximum allowable power dissipation; $P_{tot} = f(T_S)$ resp.

$$P_{tot} = f(T_A) @ R_{thJA} = 80 \text{ K/W}$$



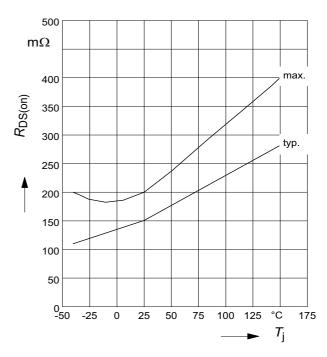
3 On-state resistance

$$R_{ON} = f(T_i); I_D = 1.4A; V_{IN} = 5V$$



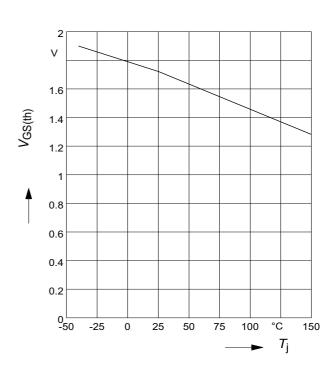
2 On-state resistance

$$R_{ON} = f(T_j); I_D = 1.4A; V_{IN} = 10V$$



4 Typ. input threshold voltage

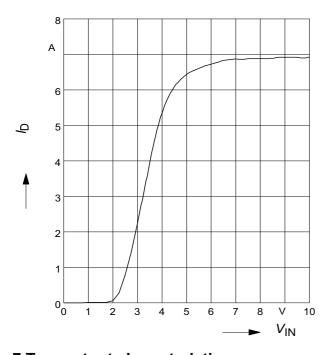
$$V_{IN(th)} = f(T_j); I_D = 0.15 \text{ mA}; V_{DS} = 12V$$





5 Typ. transfer characteristics

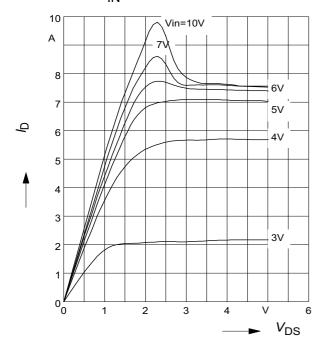
 I_D = $f(V_{IN})$; V_{DS} =12V; T_{Jstart} =25 $^{\circ}$ C



7 Typ. output characteristics

I_D=f(V_{DS}); T_{Jstart}=25°C

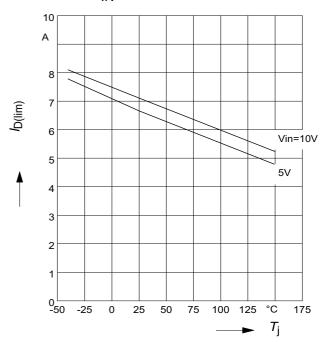
Parameter: V_{IN}



6 Typ. short circuit current

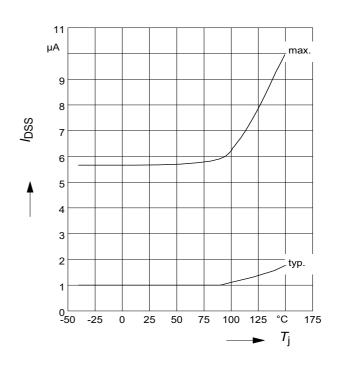
 $I_{D(lim)} = f(Tj); V_{DS} = 12V$

Parameter: V_{IN}



8 Typ. off-state drain current

 $I_{\text{DSS}} = f(T_{j})$

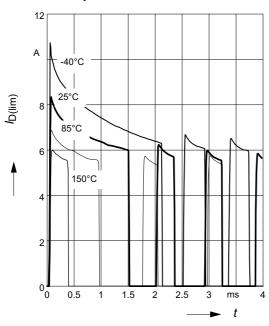




9 Typ. overload current

 $I_{D(lim)} = f(t)$, $V_{bb} = 12$ V, no heatsink

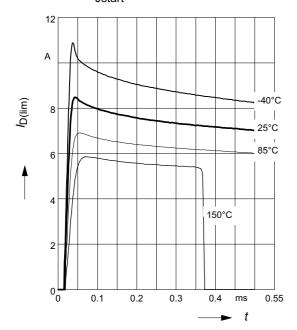
Parameter: T_{jstart}



11 Determination of I_{D(lim)}

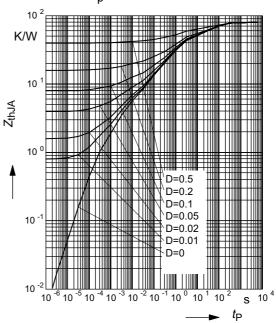
 $I_{D(lim)} = f(t); t_m = 200 \mu s$

Parameter: T_{Jstart}



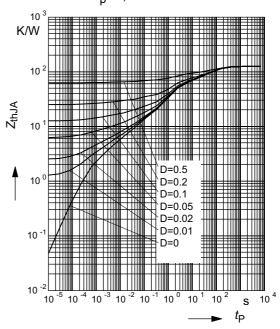
10 Typ. transient thermal impedance $Z_{\text{thJA}} = f(t_{\text{p}}) @ 6 \text{ cm}^2 \text{ cooling area}$

Parameter: $D=t_p/T$; one channel on



12 Typ. transient thermal impedance $Z_{\text{thJA}} = f(t_{\text{p}}) @ 6 \text{ cm}^2 \text{ cooling area}$

Parameter: $D=t_p/T$; both channels on





Package Outlines

1 Package Outlines

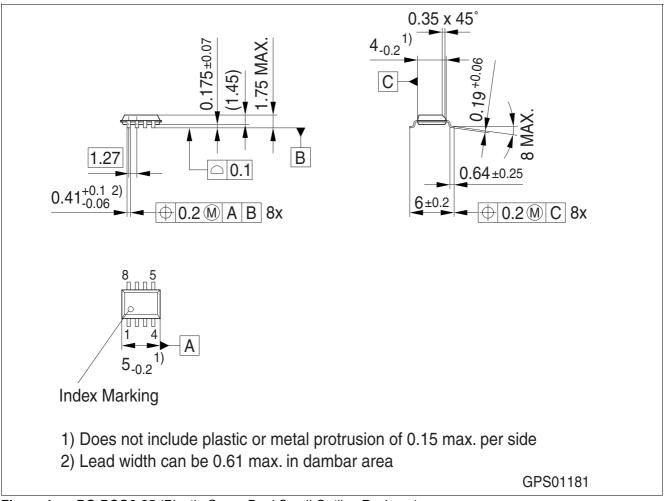


Figure 1 PG-DSO8-25 (Plastic Green Dual Small Outline Package)

Green Product (RoHS compliant)

To meet the world-wide customer requirements for environmentally friendly products and to be compliant with government regulations the device is available as a green product. Green products are RoHS-Compliant (i.e Pb-free finish on leads and suitable for Pb-free soldering according to IPC/JEDEC J-STD-020).

Please specify the package needed (e.g. green package) when placing an order

For further information on alternative packages, please visit our website: http://www.infineon.com/packages.

Dimensions in mm



Revision History

2 Revision History

| Version | Date | Changes |
|----------|------------|--|
| Rev. 1.3 | 2007-11-06 | updated package drawing of green package |
| Rev. 1.2 | 2007-06-18 | released automotive green version Package parameter (humidity and climatic) removed in Maximum ratings AEC icon added RoHS icon added Green product (RoHS-compliant) added to the feature list Package information updated to green package naming Green explanation added |
| Rev. 1.1 | 2004-03-05 | released production version |
| | | |
| | | |

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